Panasonic ideas for life

DIP6-pin type featuring high sensitivity

PhotoMOS® HS 1 Form A (AQV234)

FEATURES

1. High sensitivity

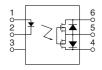
LED operate current: 0.31mA (typ.)
Recommended LED input current: 2mA

- 2. Low-level off state leakage current of max. 1 μ A
- **3. Controls low-level analog signals**PhotoMOS feature extremely low closed-circuit offset voltage to enable control of low-level analog signals without distortion.

TYPICAL APPLICATIONS

- **1. High-speed inspection machines** Scanner, IC checker, Board tester, etc.
- 2. Telephone and data communication equipment

 $\mathbf{mm} \; \mathsf{inch} \;$



RoHS compliant

TYPES

	Output rating* Package Load Load				Par					
					Through hole Surface-mount terminal				Packing quantity	
					Tape and reel packing style					
	voltage	current		Tube packing style		Picked from the 1/2/3-pin side	Picked from the 4/5/6-pin side	Tube	Tape and reel	
AC/DC dual use	400 V	120 mA	DIP6-pin	AQV234	AQV234A	AQV234AX	AQV234AZ	1 tube contains: 50 pcs. 1 batch contains: 500 pcs.	1,000 pcs.	

^{*}Indicate the peak AC and DC values.

Note: The surface mount terminal indicator "A" and the packing style indicator "X" or "Z" are not marked on the device.

RATING

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

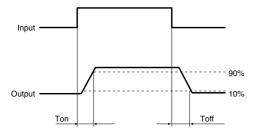
	Symbol	Type of connection	AQV234(A)	Remarks		
Input	LED forward current	lF		50 mA		
	LED reverse voltage	VR		5 V		
	Peak forward current	IFP		1 A	f = 100 Hz, Duty factor = 0.1%	
	Power dissipation	Pin		75 mW		
	Load voltage (Peak AC)	VL	1 \	400 V		
			Α	0.12 A		
	Continuous load current	l.	В	0.13 A	A connection: Peak AC, DC B. C connection: DC	
Output			С	0.15 A	B, O connection. Do	
	Peak load current	Ipeak		0.3 A	A connection: 100 ms (1 shot), V _L = DC	
	Power dissipation	Pout		500 mW		
Total power dissipation		Р⊤	1 \ [550 mW		
I/O isolation voltage		Viso] \ [1,500 V AC		
Temperature limits	Operating	Topr] \ [-40°C to +85°C -40°F to +185°F	Non-condensing at low temperature	
	Storage	Tstg	i V	-40°C to +100°C -40°F to +212°F		

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2. Electrical characteristics (Ambient temperature: 25°C 77°F)

Item			Symbol	Type of connection	AQV234(A)	Remarks
	LED anamata aurment	Typical	n IFon		0.31 mA	$\Delta I_F/\Delta t \ge Min. 100 \mu A/s$ $I_L = Max.$
	LED operate current	Maximum			0.5 mA	
Innut	LED turn off current	Minimum	Foff		0.1 mA	$\Delta I_F/\Delta t \ge Min. 100 \mu A/s$ $I_L = Max.$
Input	LED turn on current	Typical		_	0.29 mA	
	LED dropout voltage	Typical	VF		1.25 V (1.1 V at $I_F = 2 \text{ mA}$)	IF = 50 mA
	LED dropout voltage	Maximum		_	1.5 V	
		Typical	Ron	Α	30 Ω	I _F = 2 mA, I _L = Max. Within 1 s on time
		Maximum	n on	A	50 Ω	
	On resistance	Typical	Ron	В —	22.5 Ω	I _F = 2 mA, I _L = Max. Within 1 s on time
Output	On resistance	Maximum	T Non	Б	25 Ω	
		Typical	Ron	С —	11.3 Ω	I _F = 2 mA, I _L = Max. Within 1 s on time
		Maximum			12.5 Ω	
	Off state leakage current	Maximum	Leak	_	1 μΑ	$I_F = 0 \text{ mA}, V_L = \text{Max}.$
	Turn on time*	Typical	Ton		0.89 ms	I _F = 2 mA I _L = Max.
	Turn on time	Maximum		_	2 ms	
	Turn off time*	Typical	Toff		0.22 ms	I _F = 2 mA I _L = Max.
Transistor characteristics	Turn on time	Maximum			1 ms	
on landott of 15th C5	L/O consoitones	Typical	Ciso		0.8 pF	f = 1 MHz V _B = 0 V
	I/O capacitance	Maximum			1.5 pF	
	Initial I/O isolation resistance	Minimum	Riso	_	1,000 ΜΩ	500 V DC

^{*}Turn on/Turn off time



RECOMMENDED OPERATING CONDITIONS

Please obey the following conditions to ensure proper device operation and resetting.

•		<u> </u>	
Item	Symbol	Recommended value	Unit
Input LED current	lf	2	mA

- **■** For Dimensions.
- **■** For Schematic and Wiring Diagrams.
- **■** For Cautions for Use.
- These products are not designed for automotive use.

If you are considering to use these products for automotive applications, please contact your local Panasonic Corporation technical representative.

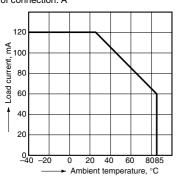
For more information.

REFERENCE DATA

1. Load current vs. ambient temperature characteristics

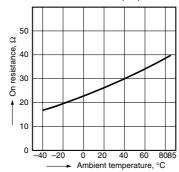
Allowable ambient temperature: -40°C to +85°C -40°F to +185°F

Type of connection: A



2. On resistance vs. ambient temperature characteristics

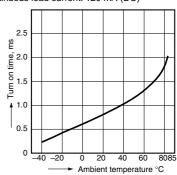
Measured portion: between terminals 4 and 6; LED current: 2 mA; Load voltage: 400 V (DC); Continuous load current: 120 mA (DC)



3. Turn on time vs. ambient temperature characteristics

LED current: 2 mA; Load voltage: 400 V (DC); Continuous load current: 120

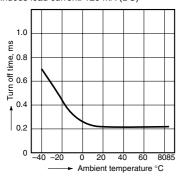
Continuous load current: 120 mA (DC)



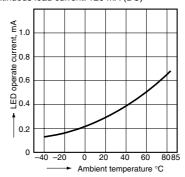
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4. Turn off time vs. ambient temperature characteristics

LED current: 2 mA; Load voltage: 400 V (DC); Continuous load current: 120 mA (DC)

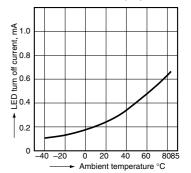


5. LED operate current vs. ambient temperature characteristics Load voltage: 400 V (DC); Continuous load current: 120 mA (DC)

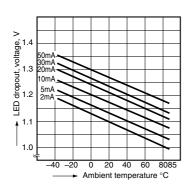


6. LED turn off current vs. ambient temperature characteristics

Load voltage: 400 V (DC); Continuous load current: 120 mA (DC)

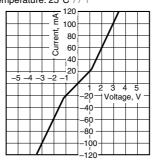


7. LED dropout voltage vs. ambient temperature characteristics LED current: 2 to 50 mA



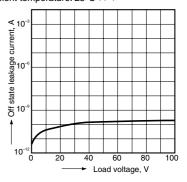
8. Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 4 and 6; Ambient temperature: 25°C 77°F



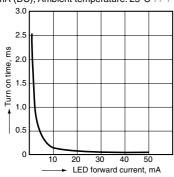
9. Off state leakage current vs. load voltage characteristics

Measured portion: between terminals 4 and 6; Ambient temperature: 25°C 77°F



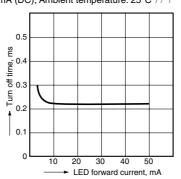
10. Turn on time vs. LED forward current characteristics

Measured portion: between terminals 4 and 6; Load voltage: 400 V (DC); Continuous load current: 120 mA (DC); Ambient temperature: 25°C 77°F



Turn off time vs. LED forward current characteristics

Measured portion: between terminals 4 and 6; Load voltage: 400 V (DC); Continuous load current: 120 mA (DC); Ambient temperature: 25°C 77°F



12. Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 4 and 6; Frequency: 1 MHz; Ambient temperature: 25°C $77^{\circ}F$

Ambient temperature: 25°C //°F

